

Reflective Optical Sensor with PIN Photodiode Output

Description

The TCND5000 is a reflective sensor that includes an infrared emitter and PIN photodiode in a surface mount package which blocks visible light.

Features

Package type: Surface mountDetector type: PIN Photodiode



L 6 mm x W 4.3 mm x H 3.75 mm

· Peak operating distance: 6 mm

• Peak operating range: 2 mm to 25 mm

• Typical output current under test: $I_{ra} > 0.11 \mu A$

• Daylight blocking filter

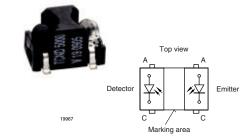
· High linearity

• Emitter wavelength 940 nm

• Lead (Pb)-free soldering released

 Lead (Pb)-free component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

• Minimum order quantity 2000 pcs, 2000 pcs/reel



Applications

- · Proximity sensor
- · Object sensor
- Motion sensor
- Touch key

Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Input (Emitter)

Parameter	Test condition	Symbol	Value	Unit
Reverse Voltage		V_{R}	5	V
Forward current		I _F	100	mA
Peak Forward Current	$t_p = 50 \mu s$, T = 2 ms, $T_{amb} = 25 ^{\circ} C$	I _{FM}	500	mA
Power Dissipation		P_V	190	mW
Junction Temperature		T _j	100	°C

Output (Detector)

Parameter	Test condition	Symbol	Value	Unit
Reverse Voltage		V_R	60	V
Power Dissipation		P _V	75	mW
Junction Temperature		T _j	100	°C

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Sensor

Parameter	Test condition	Symbol	Value	Unit
Operating Temperature Range		T _{amb}	- 40 to + 85	°C
Storage Temperature Range		T _{stg}	- 40 to + 100	°C
Soldering Temperature	acc. fig. 14	T _{sd}	260	°C

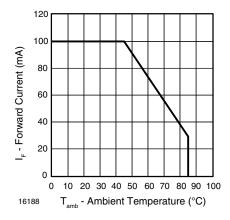


Figure 1. Forward Current Limit vs. Ambient Temperature

Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Input (Emitter)

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward Voltage	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	V_{F}		1.2	1.5	V
Temp. Coefficient of V _F	I _F = 1 mA	TK _{VF}		- 1.3		mV/K
Reverse Current	V _R = 5 V	I _R			10	μΑ
Junction Capacitance	V _R = 0 V, f = 1 MHz, E = 0	C _j		25		pF
Radiant Intensity	I _F = 20 mA, t _p = 20 ms	I _e		7	75	mW/sr
Angle of Half Intensity		φ		± 12		deg
Peak Wavelength	I _F = 100 mA	λ_{p}	930	940		nm
Spectral Bandwidth	I _F = 100 mA	Δλ		50		nm
Temp. Coefficient of λ_p	I _F = 100 mA	TKλ _p		0.2		nm/K
Rise Time	I _F = 100 mA	t _r		800		ns
Fall Time	I _F = 100 mA	t _f		800		ns
Virtual Source Diameter	Method: 63 % encircled energy	Ø		1.2		mm

see figures 2 to 8 accordingly

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Output (Detector)

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward Voltage	I _F = 50 mA	V _F		1.0	1.3	٧
Breakdown Voltage	I _R = 100 μA	V_{BR}	60			V
Reverse Dark Current	V _R = 10 V, E = 0	I _{ro}		1	10	nA
Diode capacitance	V _R = 5 V, f = 1 MHz, E = 0	C _D		1.8		pF
Reverse Light Current	$E_e = 1 \text{ mW/cm}^2$ $\lambda = 950 \text{ nm}, V_R = 5 \text{ V}$	I _{ra}		12		μΑ
Temp. Coefficient of I _{ra}	$V_R = 5 \text{ V}, \ \lambda = 870 \text{ nm}$	TK _{ira}		0.2		%/K
Angle of Half Intensity		φ		± 15		deg
Wavelength of Peak Sensitivity		λ_{p}		930		nm
Range of Spectral Bandwidth		λ _{0.5}		840 to 1050		nm

see figures 9 to 12 accordingly

Sensor

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Reverse Light Current	$V_R = 2.5 \text{ V}, I_F = 20 \text{ mA}$ D = 30 mm reflective mode: see figure 2	I _{ra}	110			nA

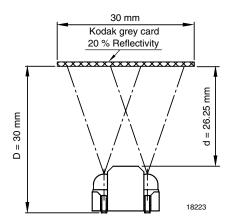


Figure 2. Test Circuit

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Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

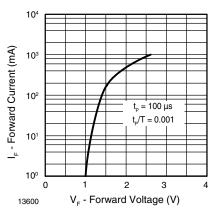


Figure 3. Forward Current vs. Forward Voltage

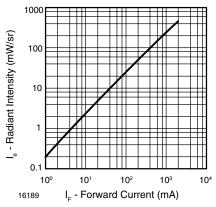


Figure 4. Radiant Intensity vs. Forward Current

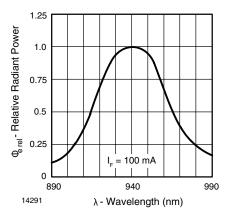


Figure 5. Relative Radiant Power vs. Wavelength

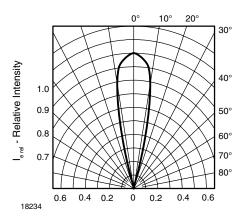


Figure 6. Relative Radiant Intensity vs. Angular Displacement

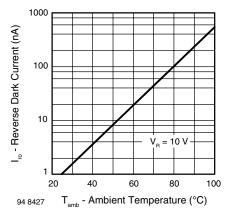


Figure 7. Reverse Dark Current vs. Ambient Temperature

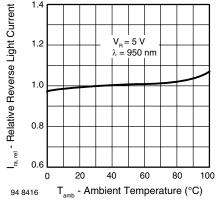


Figure 8. Relative Reverse Light Current vs. Ambient Temperature



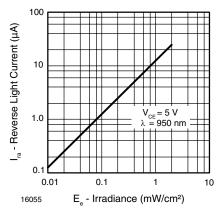


Figure 9. Reverse Light Current vs. Irradiance

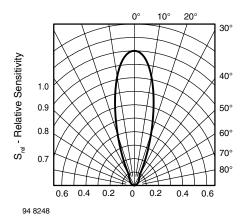


Figure 12. Relative Radiant Sensitivity vs. Angular Displacement

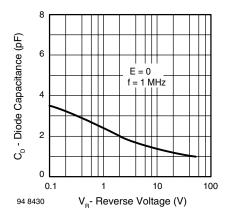


Figure 10. Diode Capacitance vs. Reverse Voltage

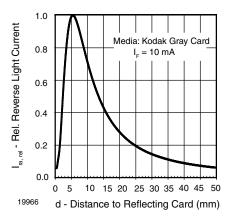


Figure 13. Relative Reverse Light Current vs. Distance

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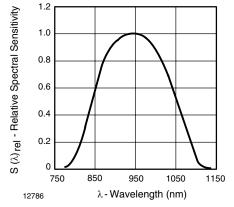
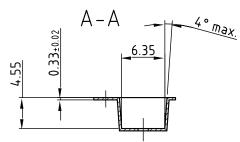
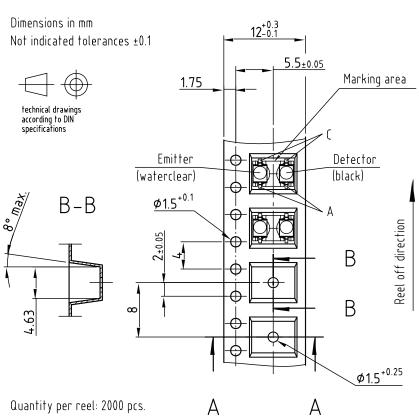


Figure 11. Relative Spectral Sensitivity vs. Wavelength

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Taping





Material of Blistertape: PC black Sealing of cavities with hot sealing cover tape, C-Pak Type CP - 2010 AS (Thickness: 0.055 - 0.075mm; Base Material: Polyester)

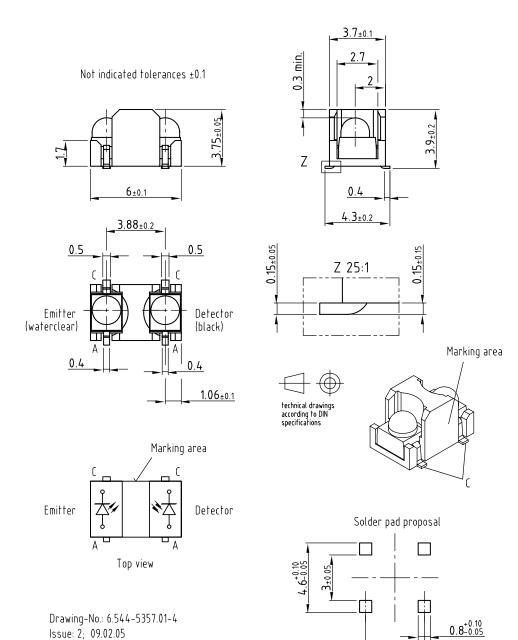
Drawing-No.: 9.700-5281.01-4

Issue: 4; 10.02.05

18222



Package Dimensions in mm



19968

3.88±0.1



Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

2. Storage

- 2.1 Storage temperature and rel. humidity conditions are: 5 $^{\circ}$ C to 30 $^{\circ}$ C, R.H. 60 $^{\circ}$
- 2.2 Floor life must not exceed 72 h, acc. to JEDEC level 4, J-STD-020.

Once the package is opened, the products should be used within 72 h. Otherwise, they should be kept in a damp proof box with desiccant.

Considering tape life, we suggest to use products within one year from production date.

- 2.3 If opened more than 72 h in an atmosphere 5 $^{\circ}$ C to 30 $^{\circ}$ C, R.H. 60 $^{\circ}$ K, devices should be treated at 60 $^{\circ}$ C \pm 5 $^{\circ}$ C for 15 hrs.
- 2.4 If humidity indicator in the package shows pink color (normal blue), then devices should be treated with the same conditions as 2.3

Reflow Solder Profiles

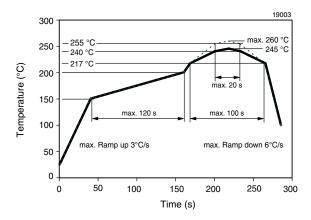


Figure 14. Lead (Pb)-Free Reflow Solder Profile

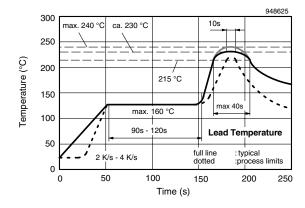


Figure 15. Lead Tin (SnPb) Reflow Solder Profile



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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